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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/050,182	03/26/1998	HIDETO OHNUMA	07977/242001	6531
7590 12/04/2002 FISH & RICHARDSON, PC 4350 LA JOLLA VILLAGE DRIVE SUITE 500			EXAMINER	
			KUNEMUND	, ROBERT M
SAN DIEGO,	CA 92122		ART UNIT	PAPER NUMBER
			1765	29
			DATE MAILED: 12/04/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

		A	
	Application No.	licant(s)	
	09/050,182	OHNUMA ET AL.	
Office Action Summary	Examiner	Art Unit	
	Robert M Kunemund	1765	
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with	the correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statute  - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).  Status	36(a). In no event, however, may a repl y within the statutory minimum of thirty ( will apply and will expire SIX (6) MONTH , cause the application to become ABAN	y be timely filed  30) days will be considered timely.  S from the mailing date of this communication.  IDONED (35 U.S.C. § 133).	
1) Responsive to communication(s) filed on 11 s	<u>September 2002</u> .		
2a)⊠ This action is <b>FINAL</b> . 2b)□ Th	is action is non-final.		
<ol> <li>Since this application is in condition for allowed closed in accordance with the practice under Disposition of Claims</li> </ol>			
4)⊠ Claim(s) <u>1-115</u> is/are pending in the application	on.		
4a) Of the above claim(s) 60-74 is/are withdraw	vn from consideration.		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1-59 and 75-115</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/o	r election requirement.		
Application Papers			
9) The specification is objected to by the Examine		F	
10) The drawing(s) filed on is/are: a) acception at the acception at the second acception	•		
Applicant may not request that any objection to the 11) The proposed drawing correction filed on	= ' '		
If approved, corrected drawings are required in re		approved by the Examiner.	
12) The oath or declaration is objected to by the Ex	•		
Priority under 35 U.S.C. §§ 119 and 120			
13) Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C. & 1	119(a)-(d) or (f)	
a) ☐ All b) ☐ Some * c) ☐ None of:	r priority under to the to	, , o(a) (a) o. (.).	
1.☐ Certified copies of the priority document	s have been received.		
2. Certified copies of the priority document		olication No.	
3. Copies of the certified copies of the prio application from the International Bu  * See the attached detailed Office action for a list	nty documents have been re reau (PCT Rule 17.2(a)).	ceived in this National Stage	
14)☐ Acknowledgment is made of a claim for domesti	•		1).
a) ☐ The translation of the foreign language pro			
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 2	5) Notice of Info	mmary (PTO-413) Paper No(s) ormal Patent Application (PTO-152)	

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## The Rejections

The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

Claims 1 to 59 and 75 to 115 are rejected under 35 U.S.C. 112, first paragraph, as containing subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention. Here is no support in the specification for a second non gettering heat treatment. The specification clearly teaches that there is a gettering step preformed which includes a second heating of the structure. A mere second heat treatment is a process which is broader in scope then the originally filed specification.

The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See In re Goodman, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); In re Longi, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); In re Van Ornum, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); In re Vogel, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and, In re Thorington, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

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A timely filed terminal disclaimer in compliance with 37 CFR 1.321© may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

Claims 1 to 59 and 76 to 115 are rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 1-31 of U.S. Patent No. 5,700,333. Although the conflicting claims are not identical, they are not patentably distinct from each other because the difference is the device formed and heating. However, in the absence of unobvious results, it would have been obvious to one of ordinary skill in the art to determine through routine experimentation the optimum, operable device formed as the instant claims form any device and heating in order to decrease heating time.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to

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the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103© and potential 35 U.S.C. 102(f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1 to 16, 76, 77, 82 to 108, and 112 to 115 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamazaki et al (5,700,333)...

The Yamazaki et al reference teaches a method of device formation. On a substrate, a layer of amorphous silicon is deposited and then catalysts are placed in contact with the silicon. The silicon is heated in order to crystallize the silicon. Then a gettering agent is added to the silicon layer. Then the structure is reheated to remove the catalyst. The second heating step is around 550°c, note entire reference. The sole difference between the instant claims and the prior art is the device formed. However, in the absence of unobvious results, it would have been obvious to one of ordinary skill in the art to determine through routine experimentation the optimum, operable types of devices made in the Yamazaki et al reference in order to create devices with low impurity silicon layer.

Claims 17 to 59, 75, 78 to 81 and 109 to 111 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamazaki et al (5,700,333) in view of Zhang et al (5,569,936)

The Yamazaki et al reference is relied on for the same reasons as stated, supra, and differs from the instant claims in the use of lasers to crystallize the silicon. However, the Zhang et al reference teaches catalyst crystallization of amorphous silicon by using lasers, note figures. It

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would have been obvious to one of ordinary skill in the art to modify the Yamazaki et al reference by the teachings of the Zhang et al reference to use lasers in order to decrease the time of crystallization.

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## Response to Applicants' Arguments

Applicant's arguments filed September 11, 2002 have been fully considered but they are not persuasive.

Applicants' argument concerning the gettering in view of the references is noted. However, the Yamazaki reference claims gettering a region or layer claim 1, this means that an area or patterning of the gettering metal is found in the reference. If there is a claimed limitation of a layer and a region, the region cannot be considered an entire layer. Also, at col 6 of the Yamazaki et al reference, it is taught to remove the areas, not layer, where the catalyst has been gettered to the metal. This removal would inherently leave islands. This is further supported by the newly submitted references of July 10, 2002, where it is clearly taught that the metal will move towards the gettering material, horizontal if the getter is in a small area, 6,251,172 and 5,961,743. Therefore, the reference does in fact render the instantly filed claims obvious to one of ordinary skill in the art. There is no teaching in the reference at any point that a region would be considered to be the entire layer as argued.

Applicants' argument concerning the Zhang et al reference is noted. However, the Zhang et al reference is merely relied on to show that the use of lasers to crystallize is well known and conventional in the art.

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The information disclosure statement of September 24, 2002 will not be considered as it is not proper. Applicants have in fact received a Office Action prior to the submission. The response to the first Office Action was filed prior to the IDS filing in question.

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THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time

policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE

MONTHS from the mailing date of this action. In the event a first reply is filed within TWO

MONTHS of the mailing date of this final action and the advisory action is not mailed until after

the end of the THREE-MONTH shortened statutory period, then the shortened statutory period

will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR

1.136(a) will be calculated from the mailing date of the advisory action. In no event, however,

will the statutory period for reply expire later than SIX MONTHS from the mailing date of this

final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Robert Kunemund whose telephone number is (703) 308-1091. The

examiner can normally be reached on Monday through Friday from 7:00 to 3:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Ben Utech, can be reached on (703) 308-3836. The fax phone number for this Group is (703)

305-6357.

Any inquiry of a general nature or relating to the status of this application or proceeding should be

directed to the Group receptionist whose telephone number is (703) 308-0661.

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RMK

December 2, 2002

ROBERT KUNEMUND PRIMARY EXAMINER